2nd Generation thinQ!™ SiC Schottky Diode

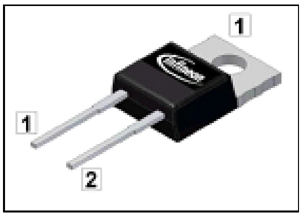
Product Summary

V_{DC}	600	V
Q_c	8	nC
I_F	4	A

Features

- Revolutionary semiconductor material - Silicon Carbide
- Switching behavior benchmark
- No reverse recovery/ No forward recovery
- No temperature influence on the switching behavior
- High surge current capability
- Pb-free lead plating; RoHS compliant
- Qualified according to JEDEC[1)] for target applications
- Breakdown voltage tested at 5mA[2)]

PG-TO220-2



thinQ! 2G Diode specially designed for fast switching applications like:

- CCM PFC
- Motor Drives

Type	Package	Marking	Pin 1	Pin 2
IDH04S60C	PG-TO220-2	D04S60C	C	A

Maximum ratings, at T_j=25 °C, unless otherwise specified

Parameter	Symbol	Conditions	Value	Unit
Continuous forward current	I_F	T_C<140 °C	4	A
RMS forward current	$I_{F,RMS}$	f=50 Hz	5.6	
reasonably be expected to cause the failure of that life-support , automotive, aviation and	$I_{F,SM}$	T_C=25 °C, t_p=10 ms	32	
Life support systems are intended to b	$I_{F,RM}$	T_j=150 °C, T_C=100 °C, D=0.1	18	
and sustain and/or protect human life.	$I_{F,max}$	T_C=25 °C, t_p=10 µs	132	
of the user or other persons may be e	V_{RRM}		600	V
Diode dv/dt ruggedness	dv/dt	V_R = 0….480V	50	V/ns
Power dissipation	P_{tot}	T_C=25 °C	42	W
Operating and storage temperature	T_j, T_{stg}		-55 ... 175	°C
Mounting torque		M3 and M3.5 screws	60	Mcm
Soldering temperature, wavesoldering only allowed at leads	T_{sold}	1.6mm (0.063 in.) from case for 10s	260	°C

Parameter	Symbol	Conditions	Values			Unit
			min.	typ.	max.	
Thermal characteristics						
Thermal resistance, junction - case	R_{thJC}		-	-	3.6	K/W
Thermal resistance, junction - ambient	R_{thJA}	leaded	-	-	62	
Electrical characteristics, at T_j=25 °C, unless otherwise specified						
Static characteristics						
DC blocking voltage	V_{DC}	I_R=0.05 mA	600	-	-	V
Diode forward voltage	V_F	I_F=4 A, T_j=25 °C	-	1.7	1.9	
		I_F=4 A, T_j=150 °C	-	2	2.4	
Reverse current	I_R	V_R=600 V, T_j=25 °C	-	0.5	50	µA
		V_R=600 V, T_j=150 °C	-	2	500	

Infineon Technologies components may be used in life-support devices or systems

and/or automotive, aviation and aerospace applications or systems only with

reasonably be expected to cause the f	Q_c	V_R=400 V, $I_F \le I_{F,max}$, di_F/dt=200 A/µs, T_j=150 °C	-	8	-	nC
aerospace device or system or to affect the saf						
Life support systems are intended to b	t_c		-	-	<10	ns
and sustain and/or protect human life.	C	V_R=1 V, f= MHz	-	130	-	pF
of the user or other persons may be endangered.		V_R=600 V, f=1 MHz	-	20	-	

[1)] J-STD20 and JESD22

[2)] All devices tested under avalanche conditions, for a time periode of 5ms, at 5mA.

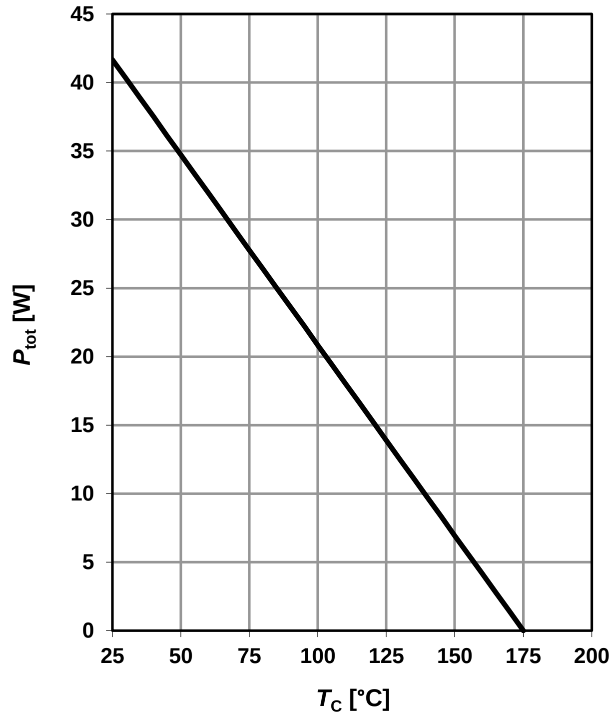
[3)] t_c is the time constant for the capacitive displacement current waveform (independent from T_j, I_{LOAD} and di/dt), different from t_{rr}, which is dependent on T_j, I_{LOAD}, di/dt. No reverse recovery time constant t_{rr} due to absence of minority carrier injection.

[4)] Only capacitive charge occuring, guaranteed by design.

1 Power dissipation

P_{tot}=f(T_C)

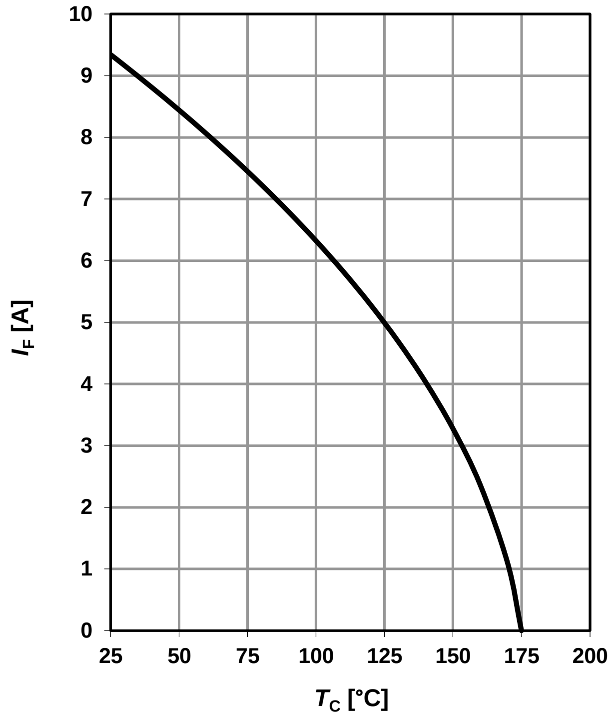
parameter: $R_{thJC(max)}$



2 Diode forward current

I_F=f(T_C); T_j≤175 °C

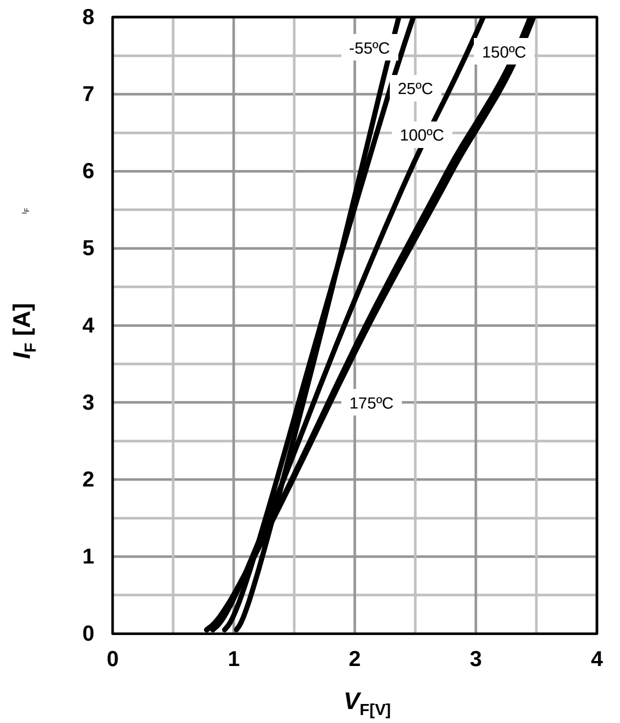
parameter: $R_{thJC(max)}$; $V_{F(max)}$



3 Typ. forward characteristic

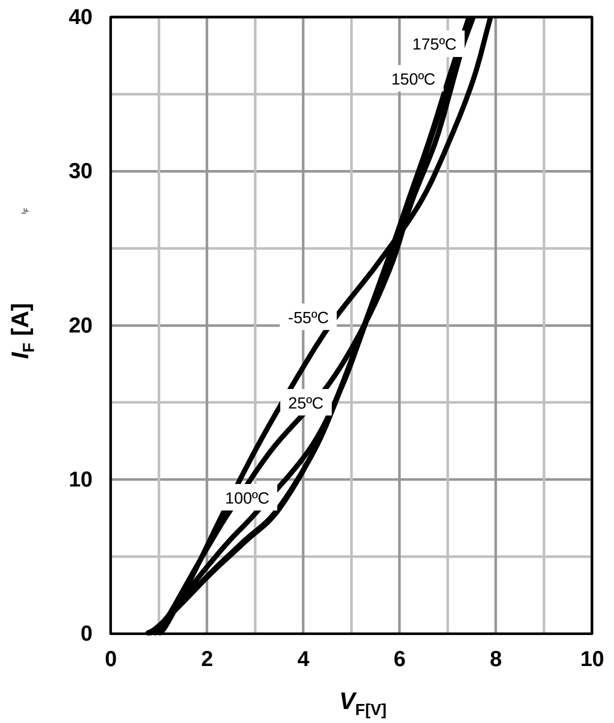
I_F=f(V_F); t_p=400 µs

parameter: T_j



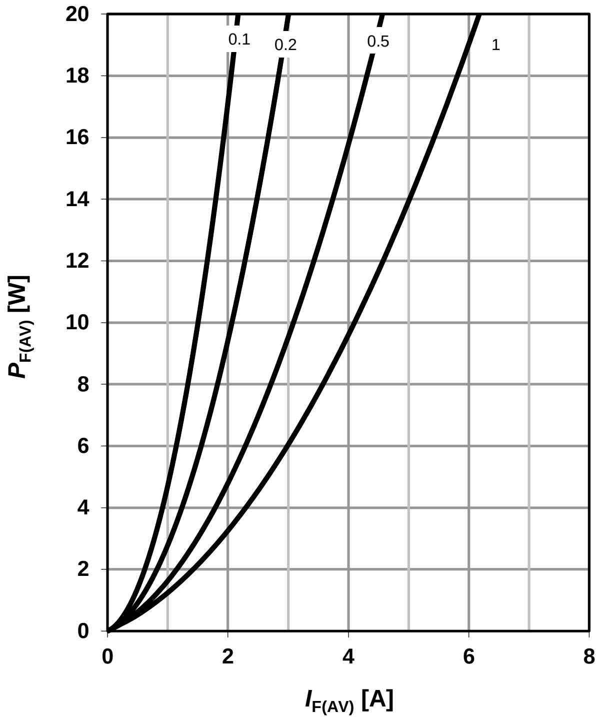
4 Typ. forward characteristic in surge current mode

I_F=f(V_F); t_p=400 µs; parameter: T_j



5 Typ. forward power dissipation vs. average forward current

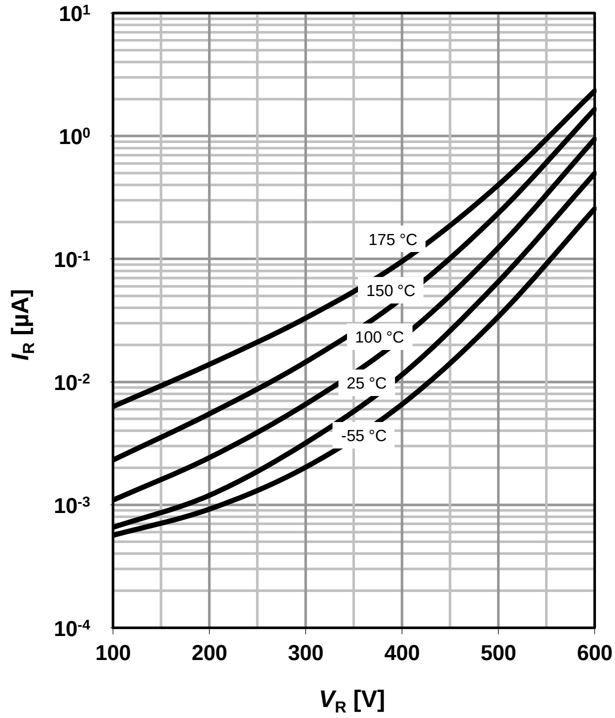
$P_{F,AV}$=f(I_F), T_C=100 °C, parameter: $D=t_p/T$



6 Typ. reverse current vs. reverse voltage

I_R=f(V_R)

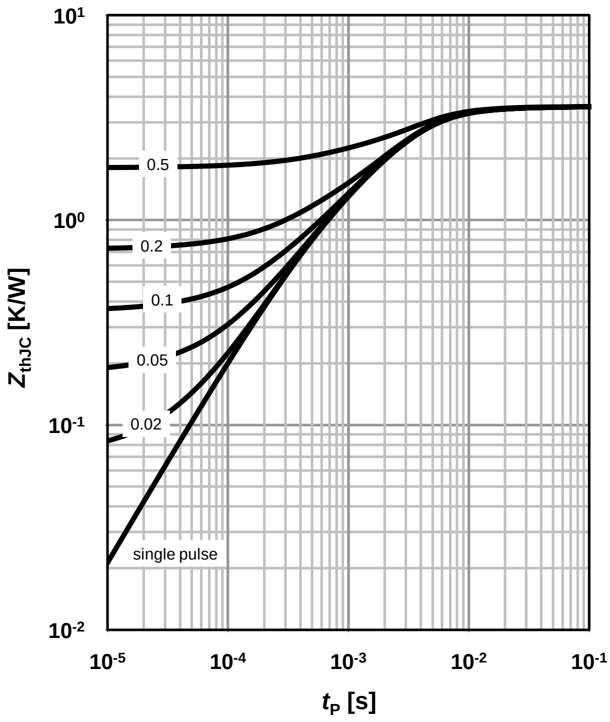
parameter: T_j



7 Transient thermal impedance

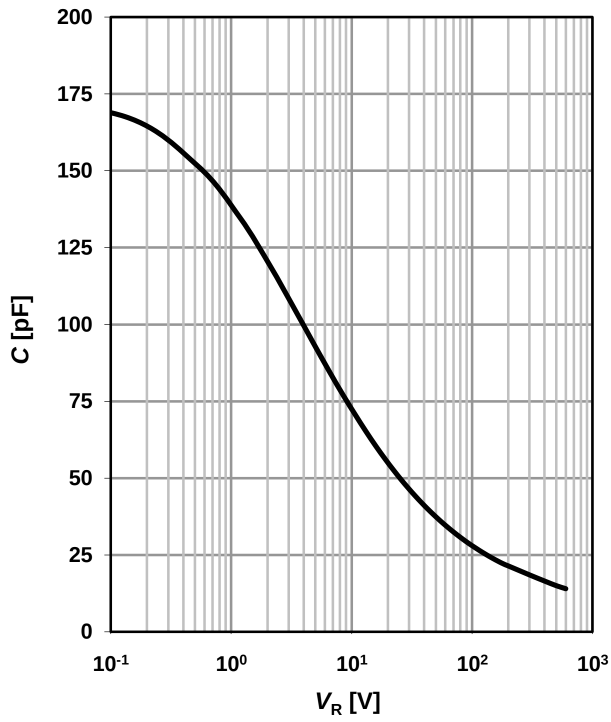
Z_{thJC}=f(t_p)

parameter: $D=t_p/T$



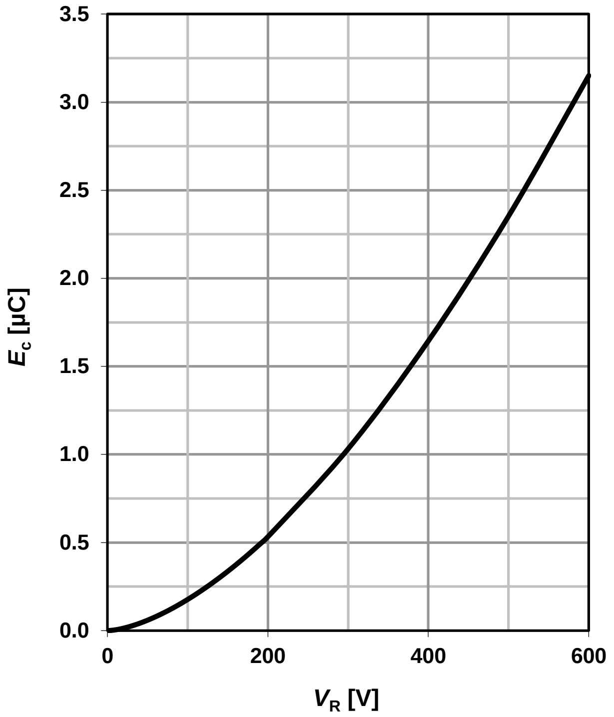
8 Typ. capacitance vs. reverse voltage

C=f(V_R); T_C=25 °C, f=1 MHz



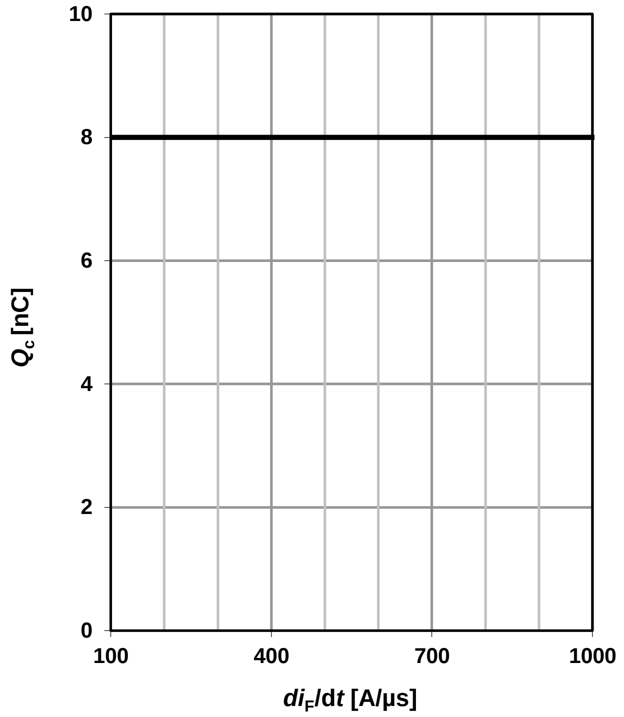
9 Typ. C stored energy

E_C=f(V_R)

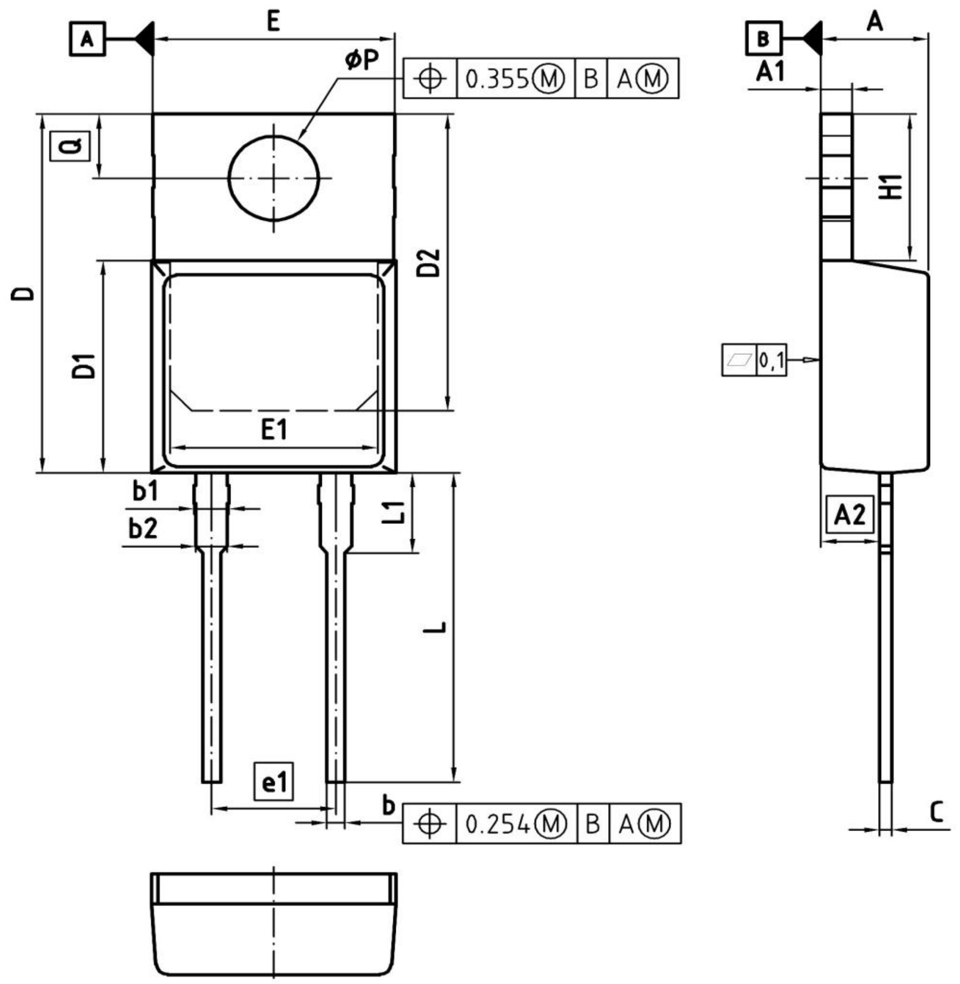


10 Typ. capacitance charge vs. current slope

Q_C=f(di_F/dt)[4]; T_j=150 °C; $I_F \leq I_{F,max}$



PG-TO220-2: Outline



DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.30	4.50	0.169	0.177
A1	1.17	1.37	0.046	0.054
A2	2.30	2.50	0.091	0.098
b	0.65	0.85	0.026	0.033
b1	1.19	1.69	0.047	0.066
b2	1.19	1.39	0.047	0.055
c	0.40	0.60	0.016	0.024
D	15.35	15.95	0.604	0.628
D1	9.05	9.45	0.356	0.372
D2	12.30	13.05	0.484	0.514
E	9.80	10.20	0.386	0.402
E1	7.25	8.60	0.285	0.339
e1	5.08		0.200	
N	2		2	
H1	5.90	6.90	0.232	0.272
L	13.00	14.00	0.512	0.551
L1	3.30	3.70	0.130	0.146
øP	3.55	3.70	0.140	0.146
Q	2.60	3.00	0.102	0.118

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SCALE 0 2.5 5mm

EUROPEAN PROJECTION

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01

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